

## **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

## IXTA62N15P

### FEATURES

- Static drain-source on-resistance: R<sub>D</sub>s(on) ≤ 40mΩ
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

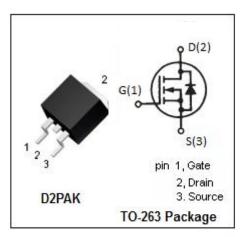
### APPLICATION

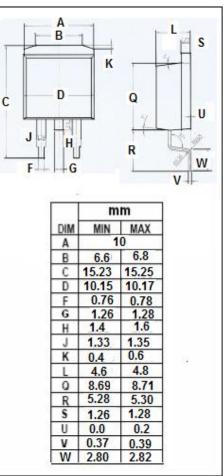
- DC/DC Converter
- · Ideal for high-frequency switching and synchronous rectification

### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

in-Source Voltage e-Source Voltage in Current-Continuous	150 ±20	V V
		V
in Current-Continuous	62	
	62	
in Current-Single Pulsed	150	А
al Dissipation @Tc=25°C	350	W
erating Junction Temperature	-55~175	°C
rage Temperature	-55~150	°C
	al Dissipation @Tc=25°C erating Junction Temperature rage Temperature	al Dissipation @T <sub>c</sub> =25°C 350 erating Junction Temperature -55~175

# • THERMAL CHARACTERISTICS SYMBOL PARAMETER MAX UNIT R<sub>th(j-c)</sub> Junction-to-case thermal resistance 0.43 °C/W







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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID =250 μ A	150		V
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID =250 μ A	3.0	5.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 31A		40	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V		±100	nA
<b>1</b>	Drain Source Lookage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		25	μ Α
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;TJ=150℃		250	μų
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> = 62A; V <sub>GS</sub> = 0V		1.5	V

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